

Semiconductor Devices - Sample Question for possible exercise

1. A BJT has a base current of  $250\ \mu\text{A}$  and emitter current of  $15\text{mA}$ . Determine the collector current gain and  $\beta$ .
2. In the circuit shown in Fig.1,  $[I_{DSS}] = 4\text{mA}$ ,  $V_p = 4\text{V}$ . Find the quiescent values of  $I_D$ ,  $V_{GS}$  and  $V_{DS}$  of the FET

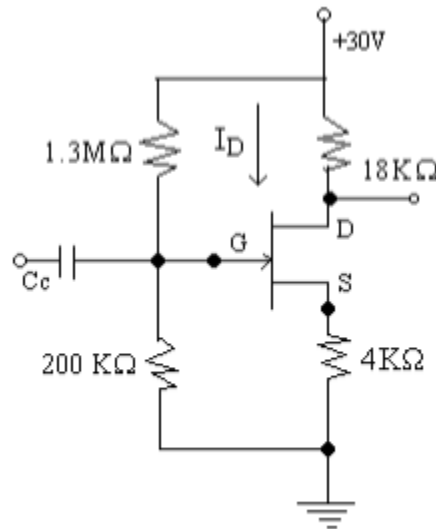
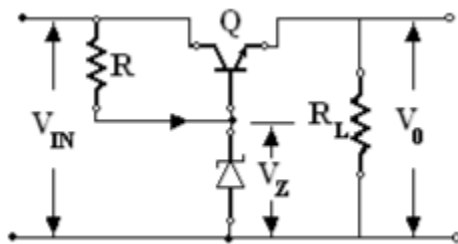


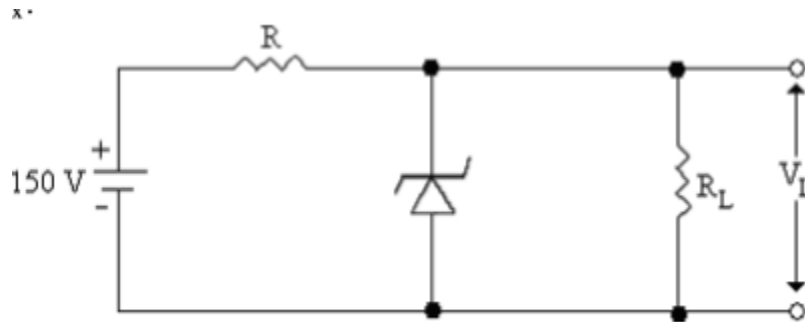
Fig.1

3. For the series regulator given below,  $V_{IN} = 15\text{V}$ ,  $R = 200\ \Omega$ , the transistor  $\beta = 50$ ,  $R_L = 1.2\ \text{k}\Omega$ ,  $V_Z = 10\text{V}$  and  $V_{BE} = 0.4\text{V}$ . Calculate (i) output voltage (ii) load current (iii) the base current in the transistor (iv) zener current.

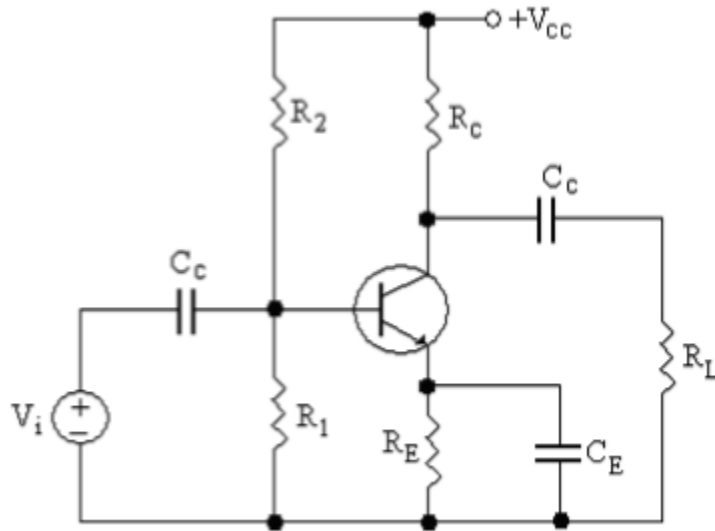


4. An intrinsic silicon bar is  $4\text{mm}$  long and has a rectangular cross section  $60 \times 100\ (\mu\text{m})^2$ . At  $300\text{K}$ , find the electric field intensity in the bar and voltage across the bar when a steady state current of  $1\ \mu\text{A}$  is measured. (Resistivity of intrinsic silicon at  $300\text{K}$  is  $2.3 \times 10^3\ \Omega\text{-m}$ )
5. The current flowing through a certain P-N junction at room temperature when reverse biased is  $0.15\ \mu\text{A}$ . Given that voltage-equivalent of temperature,  $V_T$  is  $26\text{mV}$ , and the bias voltage being very large in comparison to  $V_T$ , determine the current flowing through the diode when the applied voltage is  $0.12\text{V}$ .

6. In a transistor amplifier, change of  $0.025\text{V}$  in signal voltage causes the base current to change by  $15\mu\text{A}$  and collector current by  $1.2\text{ mA}$ . If collector and load resistances are of  $6\text{k}\Omega$  and  $12\text{k}\Omega$ , determine i) input resistance ii) current gain iii) ac load iv) voltage gain v) power gain
7. Explain 'Zener breakdown'. The zener diode in the circuit shown below regulates at  $50\text{V}$ , over a range of diode currents from  $5$  to  $40\text{mA}$ . The supply voltage  $V = 150\text{V}$ . Compute the value of  $R$  to allow voltage regulation from a zero load current to a maximum load current  $I_{\text{max}}$ . What is  $I_{\text{max}}$ ?



8. Draw a small signal equivalent circuit for the CE amplifier shown in fig below



9. Draw the symbol and characteristics of an N-channel JFET and mark linear region, saturation region and breakdown region.
10. Draw the circuits of the various transistor configurations.
11. What is an integrator? Derive the formula for its output voltage. Explain its working with neat and clean waveform i) In case of square wave input ii) In case of sine wave input
12. Derive the formula for summing amplifier and on averaging amplifier in non Inverting configuration
13. Show an FET source follower circuit. What type of negative feedback takes place in the circuit? Analyse the circuit to derive an expression for voltage gain with feedback.
14. Write the equation, which represents the boundary between the triode region and pinch off region

15. Explain how opamp can be used as the following and derive expressions for the output

- (i) Differentiator
- (ii) Integrator
- (iii) Inverting amplifier
- (iv) Summer